## **Dual General Purpose Transistor**

The NST3906DXV6T1 device is a spin-off of our popular SOT-23/SOT-323 three-leaded device. It is designed for general purpose amplifier applications and is housed in the SOT-563 six-leaded surface mount package. By putting two discrete devices in one package, this device is ideal for low-power surface mount applications where board space is at a premium.

- h<sub>FE</sub>, 100-300
- Low  $V_{CE(sat)}$ ,  $\leq 0.4 \text{ V}$
- Simplifies Circuit Design
- Reduces Board Space
- Reduces Component Count
- Lead-Free Solder Plating

#### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Collector- Emitter Voltage	V <sub>CEO</sub>	-40	Vdc
Collector- Base Voltage	V <sub>CBO</sub>	-40	Vdc
Emitter - Base Voltage	V <sub>EBO</sub>	-5.0	Vdc
Collector Current - Continuous	IC	-200	mAdc
Electrostatic Discharge	ESD	HBM>16000, MM>2000	V

#### THERMAL CHARACTERISTICS

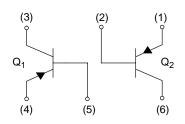
Characteristic (One Junction Heated)	Symbol	Max	Unit
Total Device Dissipation $T_A = 25^{\circ}C$	P <sub>D</sub>	357 (Note 1)	mW
Derate above 25°C		2.9 (Note 1)	mW/°C
Thermal Resistance Junction-to-Ambient	$R_{\theta JA}$	350 (Note 1)	°C/W
Characteristic			
(Both Junctions Heated)	Symbol	Max	Unit
Total Device Dissipation T <sub>A</sub> = 25°C	P <sub>D</sub>	500 (Note 1)	mW
Derate above 25°C		4.0 (Note 1)	mW/°C
Thermal Resistance Junction-to-Ambient	$R_{ heta JA}$	250 (Note 1)	°C/W
·	T <sub>J</sub> , T <sub>stg</sub>	·	°C

1. FR-4 @ Minimum Pad



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NST3906DXV6T1



SOT-563 CASE 463A PLASTIC

#### **MARKING DIAGRAM**



A2 = Specific Device Code D = Date Code

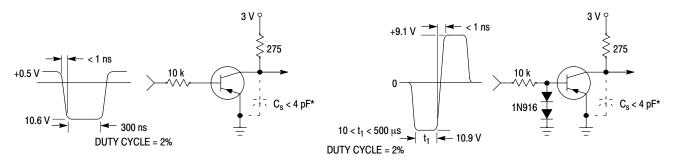
#### **ORDERING INFORMATION**

Device	Package	Shipping
NST3906DXV6T1	SOT-563	4 mm pitch 4000/Tape & Reel
NST3906DXV6T5	SOT-563	2 mm pitch 8000/Tape & Reel

#### **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTE	RISTICS				
Collector - Emitter E	Breakdown Voltage (Note 2)	V <sub>(BR)CEO</sub>	-40	-	Vdc
Collector - Base Bre	eakdown Voltage	V <sub>(BR)CBO</sub>	-40	-	Vdc
Emitter - Base Brea	akdown Voltage	V <sub>(BR)EBO</sub>	-5.0	-	Vdc
Base Cutoff Curren	t	I <sub>BL</sub>	-	-50	nAdc
Collector Cutoff Cu	rrent	I <sub>CEX</sub>	-	-50	nAdc
ON CHARACTER	RISTICS (Note 2)	•		1	II.
DC Current Gain $ (I_C = -0.1 \text{ mAdc}, \\ (I_C = -1.0 \text{ mAdc}, \\ (I_C = -10 \text{ mAdc}, \\ (I_C = -50 \text{ mAdc}, \\ (I_C = -100 \text$	$V_{CE}$ = -1.0 Vdc) $V_{CE}$ = -1.0 Vdc)	h <sub>FE</sub>	60 80 100 60 30	- 300 -	-
Collector - Emitter S (I <sub>C</sub> = -10 mAdc, (I <sub>C</sub> = -50 mAdc,	$I_B = -1.0 \text{ mAdc}$	V <sub>CE(sat)</sub>		-0.25 -0.4	Vdc
Base - Emitter Saturation Voltage ( $I_C = -10 \text{ mAdc}$ , $I_B = -1.0 \text{ mAdc}$ ) ( $I_C = -50 \text{ mAdc}$ , $I_B = -5.0 \text{ mAdc}$ )		V <sub>BE(sat)</sub>	-0.65 -	-0.85 -0.95	Vdc
SMALL- SIGNAL	CHARACTERISTICS				
Current- Gain - Ba	ndwidth Product	f <sub>T</sub>	250	-	MHz
Output Capacitance	е	C <sub>obo</sub>	-	4.5	pF
Input Capacitance C <sub>ibo</sub> -				10.0	pF
Input Impedance (V <sub>CE</sub> = -10 Vdc,	$I_C = -1.0 \text{ mAdc}, f = 1.0 \text{ kHz})$	h <sub>ie</sub>	2.0	12	kΩ
Voltage Feedback I (V <sub>CE</sub> = -10 Vdc,	h <sub>re</sub>	0.1	10	X 10 <sup>- 4</sup>	
Small- Signal Curre (V <sub>CE</sub> = -10 Vdc,	h <sub>fe</sub>	100	400	-	
Output Admittance (V <sub>CE</sub> = -10 Vdc, I <sub>C</sub> = -1.0 mAdc, f = 1.0 kHz)		h <sub>oe</sub>	3.0	60	μmhos
Noise Figure $(V_{CE} = \text{-}5.0 \text{ Vdc}, \text{ I}_{C} = \text{-}100  \mu\text{Adc}, \text{ R}_{S} = 1.0 \text{ k } \Omega, \text{ f} = 1.0 \text{ kHz})$		NF	-	4.0	dB
SWITCHING CHA	ARACTERISTICS	,			•
Delay Time	$(V_{CC} = -3.0 \text{ Vdc}, V_{BE} = 0.5 \text{ Vdc})$	t <sub>d</sub>	-	35	
Rise Time	$(I_C = -10 \text{ mAdc}, I_{B1} = -1.0 \text{ mAdc})$	t <sub>r</sub>	-	35	ns
Storage Time	$(V_{CC} = -3.0 \text{ Vdc}, I_{C} = -10 \text{ mAdc})$	t <sub>s</sub>	-	225	_
Fall Time	(l l 1 0 m/dc)	+.		75	ns

Fall Time  $(I_{B1} = I_{B2} = -1.0 \text{ mAdc})$ 2. Pulse Test: Pulse Width  $\leq 300 \ \mu s$ ; Duty Cycle  $\leq 2.0\%$ .



\* Total shunt capacitance of test jig and connectors

Figure 1. Delay and Rise Time Equivalent Test Circuit

Figure 2. Storage and Fall Time Equivalent Test Circuit

#### TYPICAL TRANSIENT CHARACTERISTICS

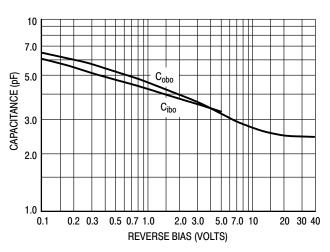


Figure 3. Capacitance

 $T_J = 25^{\circ}C$  $T_J = 125^{\circ}C$ 

Figure 4. Turn - On Time

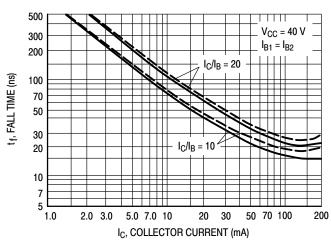
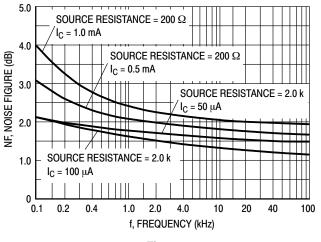


Figure 5. Fall Time

## TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

 $(V_{CE} = -5.0 \text{ Vdc}, T_A = 25^{\circ}\text{C}, Bandwidth = 1.0 \text{ Hz})$ 



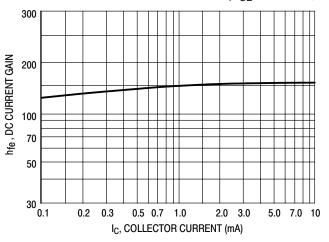
12 f = 1.0 kHz 10 NF, NOISE FIGURE (dB) 8 6 4  $I_{C} = 50 \, \mu A$  $I_C = 100 \mu A$ 2 0.1 0.2 1.0 2.0 4.0 20 40 100 10 R<sub>o</sub>, SOURCE RESISTANCE (k OHMS)

Figure 6.

Figure 7.

#### h PARAMETERS

 $(V_{CE} = -10 \text{ Vdc}, f = 1.0 \text{ kHz}, T_A = 25^{\circ}\text{C})$ 



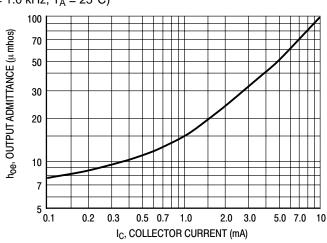
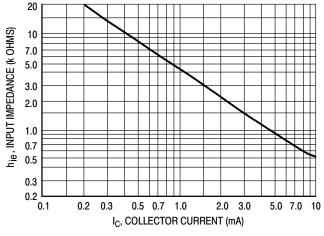


Figure 8. Current Gain

Figure 9. Output Admittance



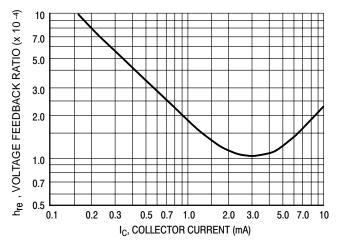


Figure 10. Input Impedance

Figure 11. Voltage Feedback Ratio

#### TYPICAL STATIC CHARACTERISTICS

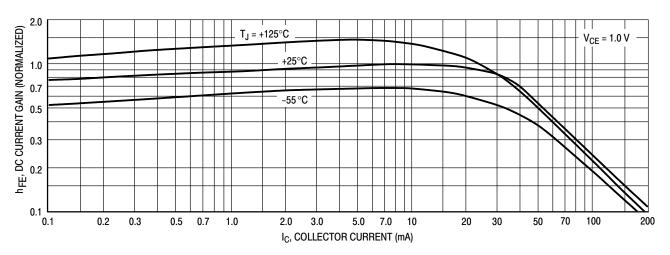


Figure 12. DC Current Gain

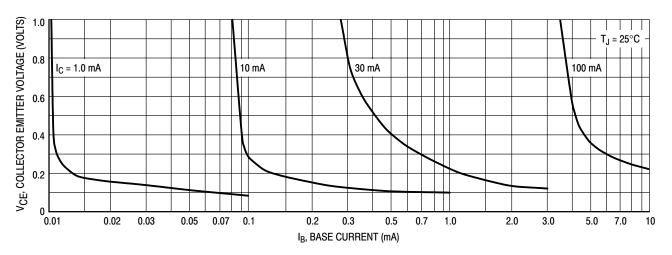


Figure 13. Collector Saturation Region

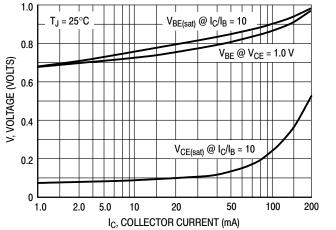
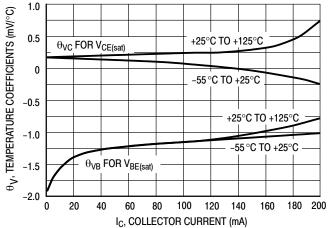


Figure 14. "ON" Voltages

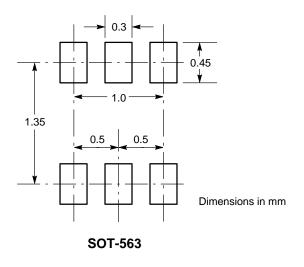


**Figure 15. Temperature Coefficients** 

# INFORMATION FOR USING THE SOT-563 SURFACE MOUNT PACKAGE MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



#### **SOT-563 POWER DISSIPATION**

The power dissipation of the SOT-563 is a function of the pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by  $T_{J(max)}$ , the maximum rated junction temperature of the die,  $R_{\theta JA}$ , the thermal resistance from the device junction to ambient, and the operating temperature,  $T_A$ . Using the values provided on the data sheet for the SOT-563 package,  $P_D$  can be calculated as follows:

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature  $T_A$  of 25°C, one can calculate the power dissipation of the device which in this case is 150 milliwatts.

$$P_D = \frac{150^{\circ}\text{C} - 25^{\circ}\text{C}}{833^{\circ}\text{C/W}} = 150 \text{ milliwatts}$$

The 833°C/W for the SOT-563 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 150 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-563 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal Clad<sup>®</sup>. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

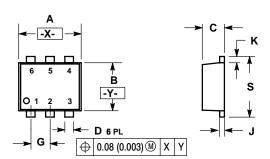
#### **SOLDERING PRECAUTIONS**

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.\*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes.
   Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.
- \* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device

#### **PACKAGE DIMENSIONS**

**SOT-563, 6 LEAD** CASE 463A-01 ISSUE O



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETERS
  3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	1.50	1.70	0.059	0.067
В	1.10	1.30	0.043	0.051
С	0.50	0.60	0.020	0.024
D	0.17	0.27	0.007	0.011
G	0.50 BSC		0.020	BSC
J	0.08	0.18	0.003	0.007
K	0.10	0.30	0.004	0.012
-	1.50	1.70	0.050	0.067

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:
PIN 1. EMITTER 1	PIN 1. EMITTER 1	PIN 1. CATHODE 1	PIN 1. COLLECTOR
2. BASE 1	2. EMITTER2	<ol><li>CATHODE 1</li></ol>	<ol><li>COLLECTOR</li></ol>
<ol><li>COLLECTOR 2</li></ol>	3. BASE 2	<ol><li>ANODE/ANODE 2</li></ol>	3. BASE
4. EMITTER 2	<ol><li>COLLECTOR 2</li></ol>	<ol><li>CATHODE 2</li></ol>	4. EMITTER
5. BASE 2	5. BASE 1	<ol><li>CATHODE 2</li></ol>	<ol><li>COLLECTOR</li></ol>
6. COLLECTOR 1	<ol><li>COLLECTOR 1</li></ol>	<ol><li>ANODE/ANODE 1</li></ol>	6. COLLECTOR

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